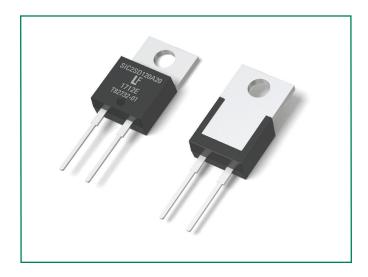
GEN2 SiC Schottky Diode LSIC2SD120A20, 1200 V, 20 A, TO-220-2L

LSIC2SD120A20









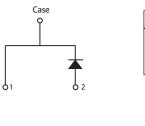
Description

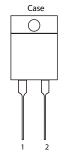
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- · Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L





Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- · Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo = P9 Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	$V_{_{\mathrm{RRM}}}$	-	1200	V	
DC Blocking Voltage	V _R	T _J = 25 °C	1200	V	
		T _C = 25 °C	54.5	А	
Continuous Forward Current	l _F	T _C = 135 °C	26.0		
		T _C = 150 °C	20.0		
Non-Repetitive Forward Surge Current	I _{FSM}	$T_C = 25 ^{\circ}\text{C}, T_P = 10 \text{ms}, \text{Half sine pulse}$	140	А	
Power Dissipation	D	T _C = 25 °C	250	W	
Fower Dissipation	P_{Tot}	T _C = 110 °C	108		
Operating Junction Temperature	$T_{_{J}}$	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

GEN2 SiC Schottky Diode LSIC2SD120A20, 1200 V, 20 A, TO-220-2L

Electrical Characteristics

		2	Value			
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Voltage V _F	I _F = 20 A, T _J = 25 °C	-	1.5	1.8	V	
	V _F	I _F = 20 A, T _J = 175 °C	-	2.2	-	V
Reverse Current I _R		$V_{R} = 1200 V, T_{J} = 25 ^{\circ}C$	-	<1	100	μΑ
	I _R	$V_R = 1200 V$, $T_J = 175 ^{\circ}C$	-	15		
Total Capacitance C		$V_R = 1 V$, $f = 1 MHz$	-	1142	-	pF
	С	V _R = 400 V, f = 1 MHz	-	108	-	
		V _R = 800 V, f = 1 MHz	-	82	-	
Total Capacitive Charge	Q _c	$V_{R} = 800 \text{ V}, Q_{C} = \int_{0}^{V_{R}} C(V) dV$	-	115	-	nC

Footnote: T₁ = +25 °C unless otherwise specified

Thermal Characteristics

		mbol Conditions	Value			
Characteristics	Symbol		Min.	Тур.	Max.	Unit
Thermal Resistance	R _{eJC}	-	-	0.6	-	°C/W

Figure 1: Typical Foward Characteristics

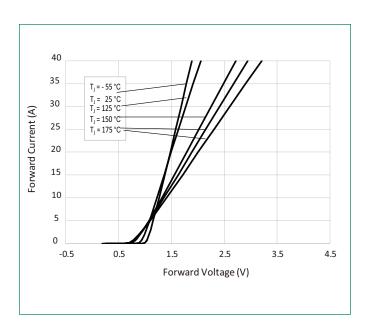


Figure 2: Typical Reverse Characteristics

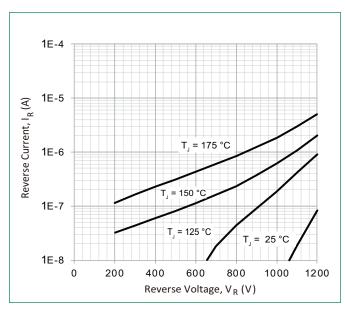




Figure 3: Power Derating

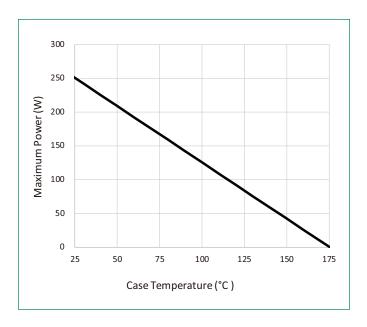


Figure 4: Current Derating

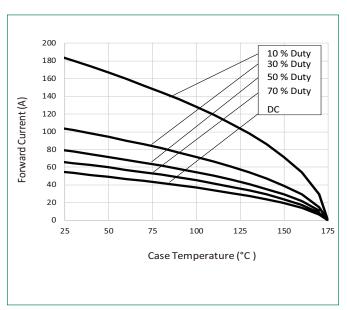


Figure 5: Capacitance vs. Reverse Voltage

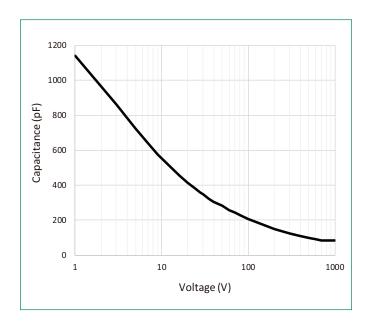


Figure 6: Capacitive Charge vs. Reverse Voltage

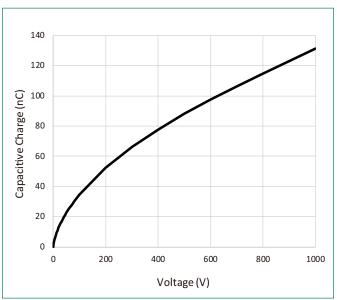




Figure 7: Stored Energy vs. Reverse Voltage

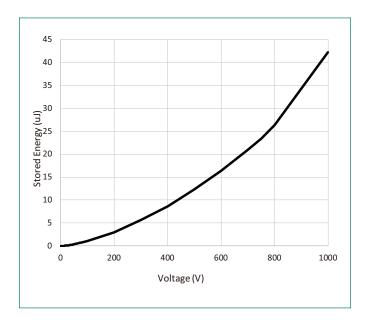
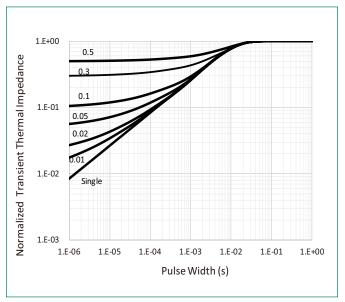
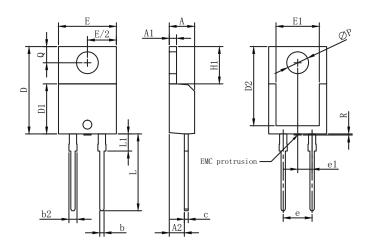


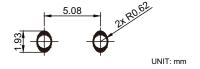
Figure 8: Transient Thermal Impedance



Dimensions-Package TO-220-2L



Recommended Solder Pad Layout



Cymbol		Millimeters	
Symbol	Min	Nom	Max
А	4.32	4.45	4.70
A1	1.14	1.27	1.40
A2	2.20	-	2.74
b	0.69	-	0.90
b2	1.17	-	1.62
С	0.36	-	0.60
D	14.90	-	15.90
D1	8.62	-	9.40
D2	12.50	-	12.95
Е	9.70	10.18	10.36
E1	7.57	7.61	8.30
e1	-	2.54	-
е	5.03	5.08	5.13
H1	6.30	6.55	6.80
L	12.88	13.50	14.00
L1	2.39	-	3.25
øΡ	3.50	3.84	3.96
Q	2.65	-	3.05
R	-	-	0.25

GEN2 SiC Schottky Diode LSIC2SD120A20, 1200 V, 20 A, TO-220-2L

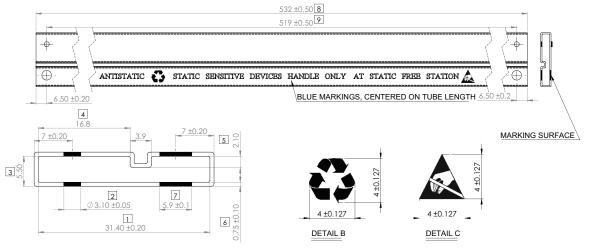
Part Numbering and Marking System

= SiC Diode SIC = Gen2 SD = Schottky Diode SIC2SD120A20 = Voltage Rating (1200 V) 120 LF = TO-220 Package (2 Lead) YYWWE 20 = Current Rating (20 A) ZZZZZZ-ZZ YY = Year WW = Week = Special Code Е ZZZZZZ-ZZ = Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A20	SIC2SD120A20	Tube	1000

Packing Specification (Tube for TO-220-2L)



- NOTES:

 1. Material transparent extruded PVC with antistatic dipping

 2. Radius: 0.5 maximum unless otherwisen specified

 3. Critical areas: Labelled in Box

 4. All pin plug holes are considered critical dimension

 5. Marking Font Type: Times new roman, 3.12 ±0.127 in height

 6. Material Thickness: 0.75 ±0.10

 7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°

 8. Unit: Millimeter (mm)

Disclaimer Notice - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse. Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littlefuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.